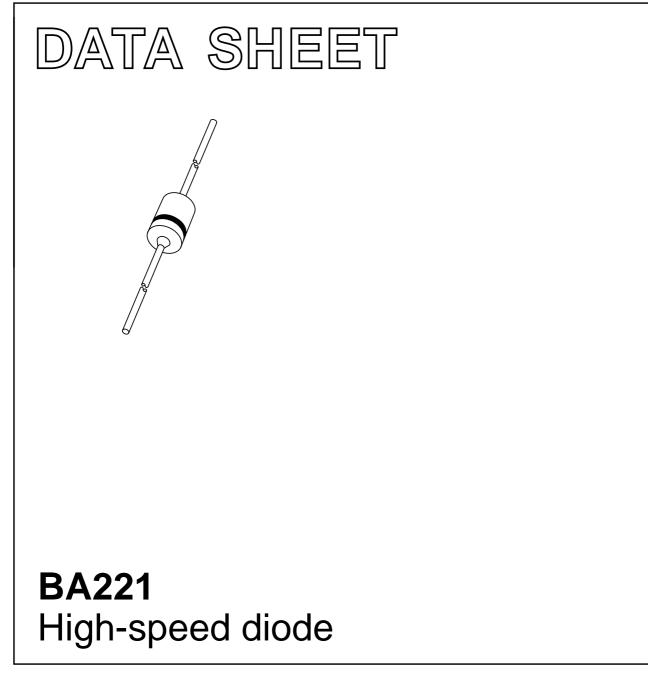
# DISCRETE SEMICONDUCTORS



Product specification Supersedes data of April 1996 1996 Sep 03



HILIP

### **BA221**

**Product specification** 

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MAM246

### FEATURES

- Hermetically sealed leaded glass SOD27 (DO-35) package
- High switching speed: max. 4 ns
- General application
- Continuous reverse voltage: max. 30 V
- Repetitive peak reverse voltage: max. 30 V
- Repetitive peak forward current: max. 400 mA.

### APPLICATIONS

• High-speed switching.

#### LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

DESCRIPTION

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The diode is type branded.

package.

The BA221 is a high-speed switching diode fabricated in planar technology,

and encapsulated in the hermetically sealed leaded glass SOD27 (DO-35)

Fig.1 Simplified outline (SOD27; DO-35) and symbol.

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V <sub>RRM</sub>	repetitive peak reverse voltage		-	30	V
V <sub>R</sub>	continuous reverse voltage		-	30	V
I <sub>F</sub>	continuous forward current	see Fig.2; note 1	-	200	mA
I <sub>FRM</sub>	repetitive peak forward current		-	400	mA
I <sub>FSM</sub>	non-repetitive peak forward current	square wave; T <sub>j</sub> = 25 °C prior to surge; see Fig.4			
		t = 1 μs	-	9	A
		t = 100 μs	-	3	A
		t = 1 s	-	1	A
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> = 25 °C; note 1	-	350	mW
T <sub>stg</sub>	storage temperature		-65	+200	°C
Tj	junction temperature		-	200	°C

#### Note

1. Device mounted on an FR4 printed circuit-board; lead length 10 mm.

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BA221

### ELECTRICAL CHARACTERISTICS

 $T_j$  = 25 °C; unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V <sub>F</sub>	forward voltage	see Fig.3			
		I <sub>F</sub> = 1 mA	_	625	mV
		I <sub>F</sub> = 100 mA	—	950	mV
		I <sub>F</sub> = 200 mA	—	1050	mV
I <sub>R</sub>	reverse current	see Fig.5			
		V <sub>R</sub> = 10 V	—	25	nA
		V <sub>R</sub> = 30 V	_	200	nA
		V <sub>R</sub> = 10 V; T <sub>j</sub> = 150 °C	_	50	μA
		V <sub>R</sub> = 30 V; T <sub>j</sub> = 150 °C	—	100	μA
C <sub>d</sub>	diode capacitance	$f = 1 MHz; V_R = 0; see Fig.6$	_	2.5	pF
t <sub>rr</sub>	reverse recovery time	when switched from $I_F = 10$ mA to $I_R = 60$ mA; $R_L = 100 \Omega$ ; measured at $I_R = 1$ mA; see Fig.7	_	4	ns
V <sub>fr</sub>	forward recovery voltage	when switched from $I_F = 400$ mA; $t_r = 30$ ns; see Fig.8	_	2.0	V

### THERMAL CHARACTERISTICS

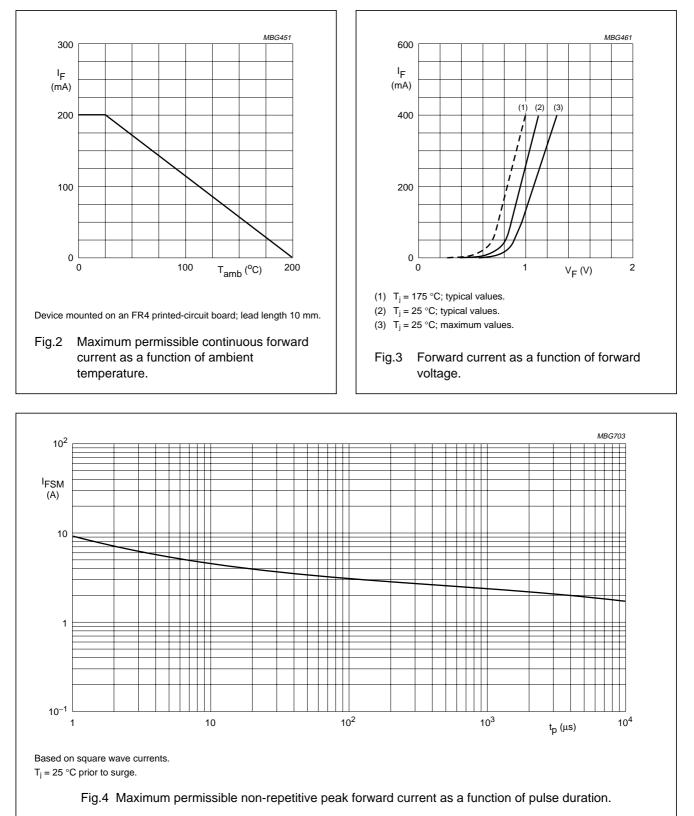
SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R <sub>th j-tp</sub>	thermal resistance from junction to tie-point	lead length 10 mm	240	K/W
R <sub>th j-a</sub>	thermal resistance from junction to ambient	lead length 10 mm; note 1	500	K/W

### Note

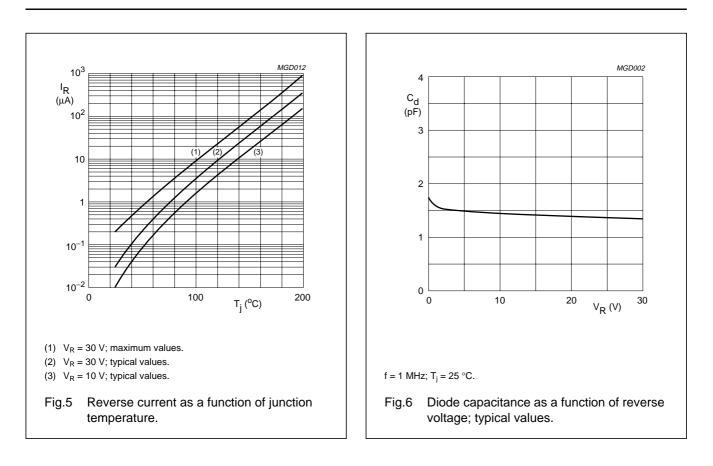
1. Device mounted on a printed circuit-board without metallization pad.

## BA221

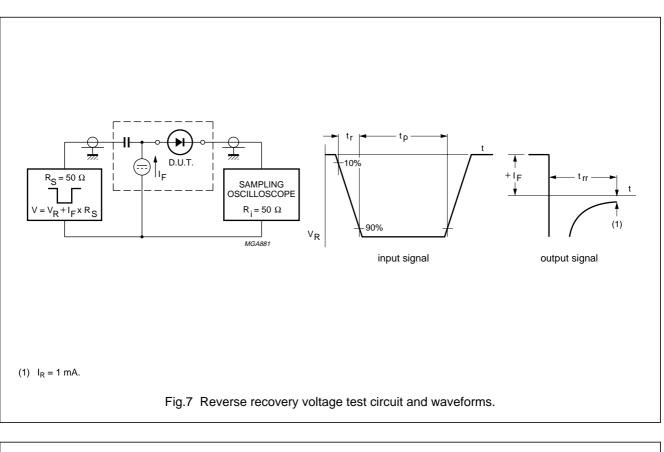
### **GRAPHICAL DATA**

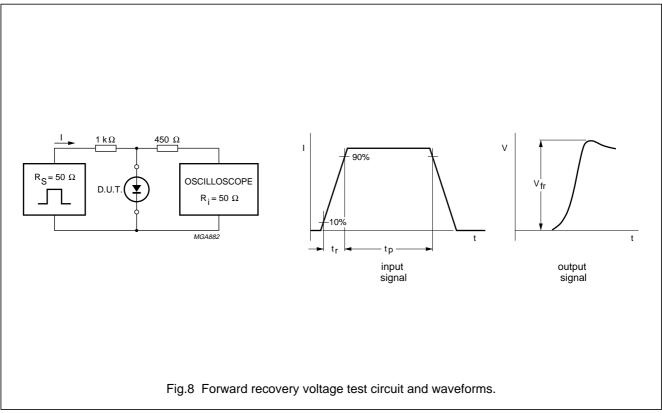


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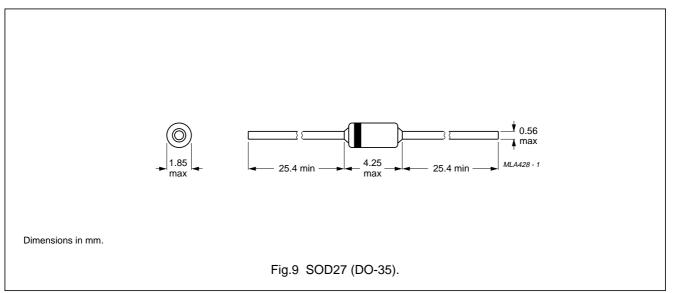
## BA221





## BA221

#### PACKAGE OUTLINE



#### DEFINITIONS

Data Sheet Status		
Objective specification	bjective specification This data sheet contains target or goal specifications for product development.	
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.	
Product specification	This data sheet contains final product specifications.	
Limiting values		
more of the limiting values m of the device at these or at a	accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or hay cause permanent damage to the device. These are stress ratings only and operation any other conditions above those given in the Characteristics sections of the specification miting values for extended periods may affect device reliability.	
Application information		
Where application information	on is given, it is advisory and does not form part of the specification.	

### LIFE SUPPORT APPLICATIONS

These products are not designed for use in life support appliances, devices, or systems where malfunction of these products can reasonably be expected to result in personal injury. Philips customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Philips for any damages resulting from such improper use or sale.